RENESAS

HD74HC1G86

2-input Exclusive-OR Gate

REJ03D0189-0500Z (Previous ADE-205-300C (Z)) Rev.5.00 Jan.27.2004

Description

The HD74HC1G86 is high-speed CMOS two input exclusive–OR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS–TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

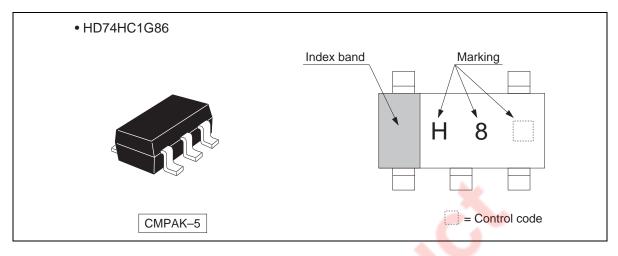
Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC86 Supply voltage range : 2 to 6 V Operating temperature range : -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

| Part Name | Package Type | Package Code | Package Abbreviation | Taping Abbreviation (Quantity) |
|---------------|--------------|--------------|-------------------------|-----------------------------------|
| HD74HC1G86CME | CMPAK-5 pin | CMPAK-5V | СМ | E (3,000 pcs/reel) |



Outline and Article Indication



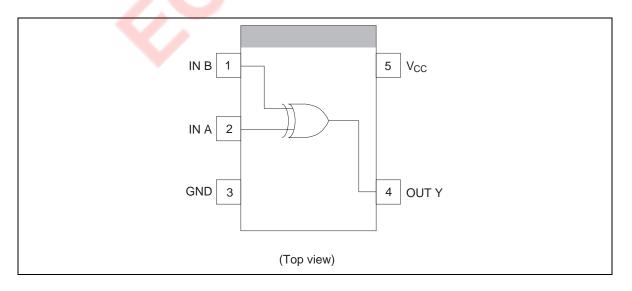
Function Table

| Inputs | | |
|--------|---|----------|
| A | В | Output Y |
| L | L | |
| L | Н | Н |
| Н | L | н |
| Н | н | |

H : High level

L : Low level

Pin Arrangement





Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit | Test Conditions |
|---|-------------------------------------|-------------------------------|------|--|
| Supply voltage range | V _{CC} | –0.5 to 7.0 | V | |
| Input voltage range *1 | VI | –0.5 to V _{CC} + 0.5 | V | |
| Output voltage range *1, 2 | Vo | –0.5 to V _{CC} + 0.5 | V | Output : H or L |
| Input clamp current | I _{IK} | ±20 | mA | $V_{I} < 0 \text{ or } V_{I} > V_{CC}$ |
| Output clamp current | Ι _{ΟΚ} | ±20 | mA | $V_0 < 0 \text{ or } V_0 > V_{CC}$ |
| Continuous output current | lo | ±25 | mA | $V_0 = 0$ to V_{CC} |
| Continuous current through V_{CC} or GND | I _{CC} or I _{GND} | ±25 | mA | ha |
| Maximum power dissipation at Ta = 25° C (in still air) ^{*3} | P _T | 200 | mW | ~ |
| Storage temperature | Tstg | -65 to 150 | °C | |

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

| Item | Symbol | Min | Мах | Unit | Test Conditions |
|------------------------|---------------------------------|-----|-----------------|------|------------------|
| Supply voltage range | Vcc | 2 | 6 | V | |
| Input voltage range | VI | 0 | V _{cc} | V | |
| Output voltage range | Vo | 0 | V _{cc} | V | |
| Output current | IOL | — | 2.0 | mA | $V_{CC} = 4.5 V$ |
| | | — | 2.6 | | $V_{CC} = 6.0 V$ |
| | I _{OH} | — | -2.0 | mA | $V_{CC} = 4.5 V$ |
| | | _ | -2.6 | | $V_{CC} = 6.0 V$ |
| Input rise / fall time | t _r , t _f | 0 | 1000 | ns | $V_{CC} = 2.0 V$ |
| (10% to 90%) | | 0 | 500 | | $V_{CC} = 4.5 V$ |
| | | 0 | 400 | | $V_{CC} = 6.0 V$ |
| Operating temperature | Та | -40 | 85 | °C | |

Note: Unused or floating inputs must be held high or low.



Electrical Characteristics

| | | Vcc | T _a = 2 | 5°C | | T _a = -40 to 85°C | | | | |
|-------------------|-----------------|-----|--------------------|------|------|------------------------------|------|------|------------------------------------|---------------------------|
| Item | Symbol | (V) | Min | Тур | Max | Min | Max | Unit | Test Con | ditions |
| Input voltage | VIH | 2.0 | 1.5 | | | 1.5 | | V | | |
| | | 4.5 | 3.15 | — | — | 3.15 | | - | | |
| | | 6.0 | 4.2 | — | _ | 4.2 | _ | _ | | |
| | VIL | 2.0 | | — | 0.5 | _ | 0.5 | _ | | |
| | | 4.5 | _ | | 1.35 | _ | 1.35 | _ | | |
| | | 6.0 | | — | 1.8 | _ | 1.8 | _ | | |
| Output voltage | V _{OH} | 2.0 | 1.9 | 2.0 | _ | 1.9 | _ | V | V _{IN} = | I _{OH} = -20 μA |
| | | 4.5 | 4.4 | 4.5 | _ | 4.4 | _ | _ | V _{IH} or V _{IL} | |
| | | 6.0 | 5.9 | 6.0 | | 5.9 | _ | | | |
| | | 4.5 | 4.18 | 4.31 | — | 4.13 | | | | $I_{OH} = -2 \text{ mA}$ |
| | | 6.0 | 5.68 | 5.80 | — | 5.63 | - | | | I _{OH} = -2.6 mA |
| | V _{OL} | 2.0 | _ | 0.0 | 0.1 | - | 0.1 | | | $I_{OL} = 20 \ \mu A$ |
| | | 4.5 | _ | 0.0 | 0.1 | - (| 0.1 | _ | | |
| | | 6.0 | | 0.0 | 0.1 | | 0.1 | _ | | |
| | | 4.5 | — | 0.17 | 0.26 | | 0.33 | _ | | $I_{OL} = 2 \text{ mA}$ |
| | | 6.0 | _ | 0.18 | 0.26 | | 0.33 | _ | | I _{OL} = 2.6 mA |
| Input current | I _{IN} | 6.0 | - < | - | ±0.1 | _ | ±1.0 | μA | $V_{IN} = V_{CC}$ or GND | |
| Operating current | I _{CC} | 6.0 | _ | | 1.0 | _ | 10.0 | μA | $V_{\rm IN} = V_{\rm CC}$ | or GND |



Switching Characteristics

| | | Ta = 25°C | | | | | |
|-------------------------|--------------------------------------|-----------|-----|-----|------|-----------------|--|
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions | |
| Output rise / fall time | t _{TLH} t _{THL} | _ | 4 | 8 | ns | Test circuit | |
| Propagation delay time | t _{PLH} t _{PHL} | — | 10 | 17 | ns | Test circuit | |

 $(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$

| | | Vcc | Ta = | 25°C | | Ta = -4 | 0 to 85°C | |
|-------------------------|--------------------------------------|-----|------|------|-----|---------|-----------|----------------------|
| Item | Symbol | (V) | Min | Тур | Max | Min | Max | Unit Test Conditions |
| Output rise / fall time | t _{TLH} t _{THL} | 2.0 | — | 50 | 125 | — | 155 | ns Test circuit |
| | | 4.5 | — | 14 | 25 | — | 31 | |
| | | 6.0 | _ | 12 | 21 | - | 26 | |
| Propagation delay time | t _{PLH} t _{PHL} | 2.0 | _ | 48 | 100 | - | 125 | ns Test circuit |
| | | 4.5 | _ | 12 | 20 | | 25 | _ |
| | | 6.0 | _ | 9 | 17 | | 21 | _ |
| Input capacitance | C _{IN} | — | — | 2.5 | 5 | - | 5 | pF |
| Equivalent capacitance | CPD | — | - | 10 | - | | _ | pF |

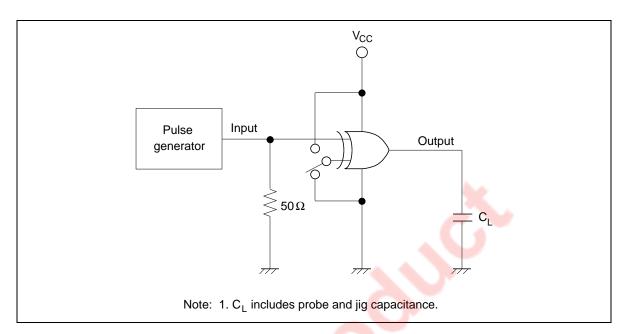
 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$

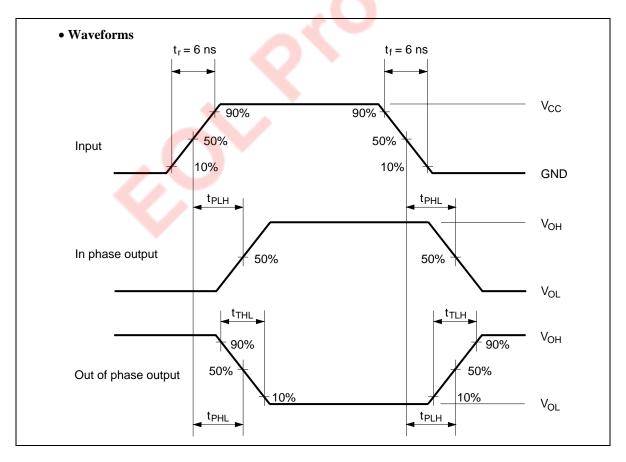
Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$



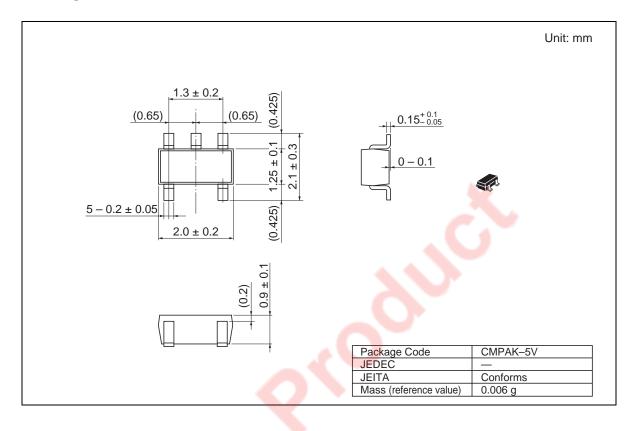
Test Circuit







Package Dimensions





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